BRIDGE RECTIFIERS



VOLTAGE:

Volts

CURRENT:

6 Ampers Package: **HBS** **Marking And Polarity**

FEATURES

- Glass Passivated Chip Junction
- Super Fast Recovery Time For High Efficiency

1000

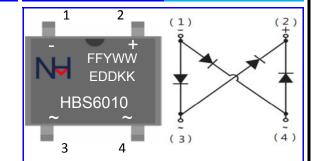
- Low Leakage Current For High Reliability
- High Forward Surge Capability For High Reliability

MECHANICAL DATA

- Package: Molding Compound Meets UL 94 V-0 Flammability Rating, RoHS-Compliant
- Polarity: As Marked On Case
- Mounting Position: Any
- Weight:App. 0.374 Grams (0.01319 Ounce)

TYPICAL APPLICATIONS

■ General Purpose Use In AC/DC BridgeFull Waverectification For PD,Adapter, Power Supply, Monitor, LED Driver, Printer, Audio Equipment, TV And Homeappliances Etc. Applications.



Remark:

- ①. NH=Niuhang Trademark
- 2. FF=Product Line Code, According To Actual Changes YWW=Date Code, According To Actual Changes EDDKK=Inernal Code,According To Actual Changes
- ③. HBS6010=Model
- 4. -~~+=Polarity Mark

Single phase,half wave,60Hz,resistive or inductive load. For capacitive load, derate current by 20%

Maximum Ratings (Ta=25℃ Unless Otherwise Specified)					
Parameter	Test Conditions	Symbol	HBS6010	Unit	
Maximum Repetitive Peak Reverse Voltage		V_{RRM}	1000	V	
Maximum RMS Voltag		V _{RMS}	700	V	
Maximum DC Blocking Voltage		V _{DC}	1000	V	
Maximum Average Forward Rectified Current	@TC= 100 °C	I _{F(AV)}	6	Α	
Peak Forward Surge Current	8.3ms Single Half Sine-wave Superimposed On Rate Load	I _{FSM}	150	Α	
Current Squared Time Per Diode	t<8.3me	I ² +	03.4	A ² 000	

Electrical Characteristcs (Ta=25℃ Unless Otherwise Specified) **HBS6010** Parameter **Test Conditions** Symbol Unit Min. Тур. Max. Ta=25℃ 0.95 1.15 ν Instaneous Forward Voltage Per Diode (note1) $I_F = 3.0$ A Ta=125℃ 0.83 1.05 Ta=25℃ $V_R = V_{RRM}$ 1.00 5.00 Maximum DC Reverse Current At Rated DC uΑ I_{RRM} Blocking Voltage (Note 1) Ta=125℃ 500.00 50.00 $V_R = 80\% * V_{RRM}$ Typical Junction Capacitance Per Diode 45.00 4.0 V,1MHz

Thermal Characteristcs (Ta=25℃ Unless Otherwise Specified)							
Parameter	Symbol		HBS6010)		Unit	
Operating Junction Temperature Range	TJ	-55	to	150		°	
Storage Temperature Range	T _{STD}	-55	to	150			
Typical Thermal Resistance (Note 2)	R _{θJA}		70.0			°C/W	
Typical Thermal Resistance (Note 2)	R _{eJC}		10.0			C/VV	

Notes: 1.Pulse Test: 300 Us Pulse Width,1% Duty Cycle

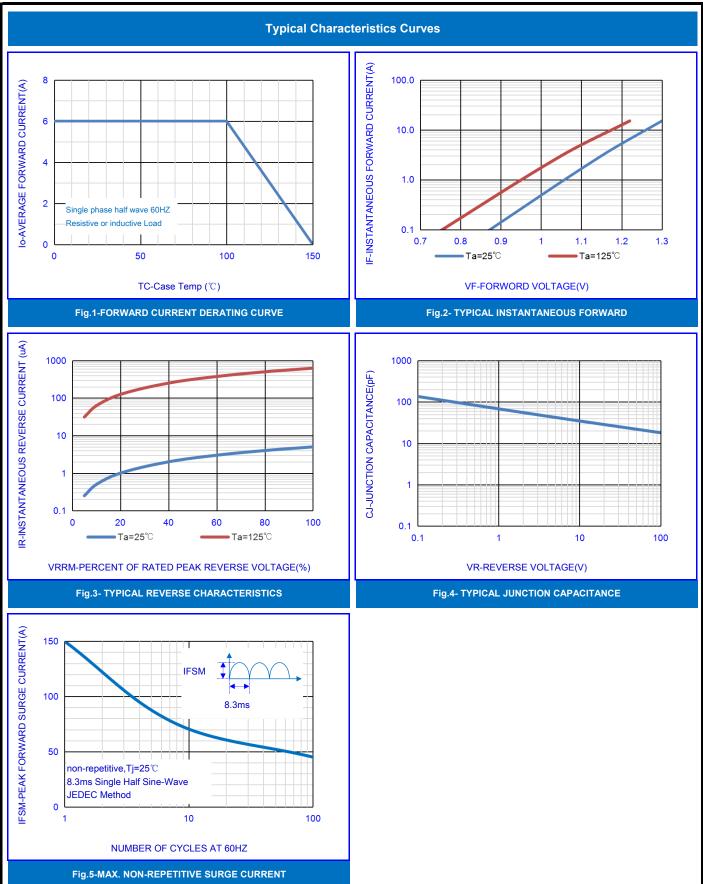
2.Device Mounted On Device Mounted On 75mm x 45mm x 5.5mm Aluminum Plate Heatsink.

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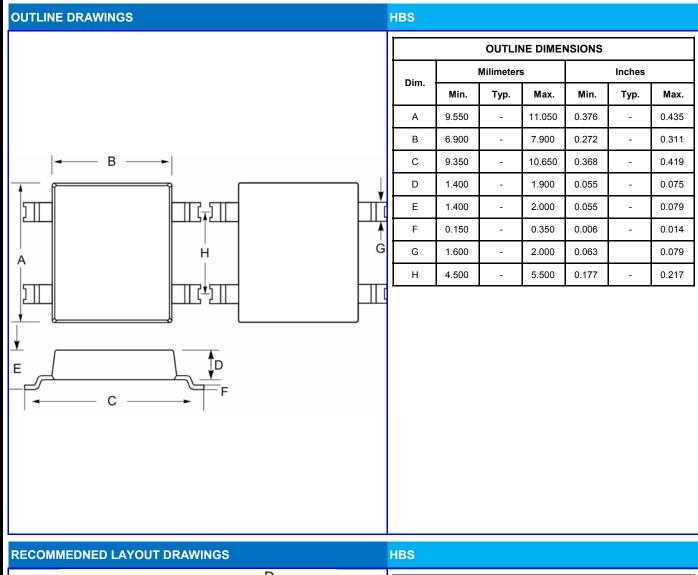


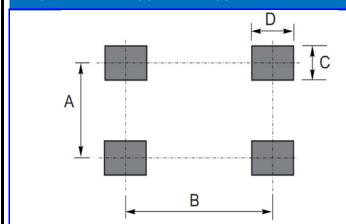




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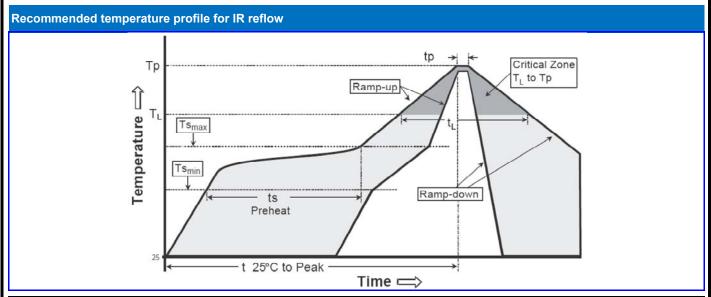
RECOMMENDED LAYOUT DIMENSIONS						
Milimeters			Inches			
Min.	Тур.	Max.	Min.	Тур.	Max.	
1	8.920	1	1	0.351	1	
-	4.500	-	1	0.177	-	
-	1.500	-	-	0.059	-	
-	2.000	-	1	0.079	-	
		Milimeters Min. Typ. - 8.920 - 4.500 - 1.500	Milimeters Min. Typ. Max. - 8.920 - - 4.500 - - 1.500 -	Milimeters Min. Typ. Max. Min. - 8.920 - - - 4.500 - - - 1.500 - -	Milimeters Inches Min. Typ. Max. Min. Typ. - 8.920 - - 0.351 - 4.500 - - 0.177 - 1.500 - - 0.059	

PACKING INFORMATION						
Package Code	Package Method	Inner Box Size L×W×H(mm)	Quantity (Pcs/Inner Box)	Outer Carton Size L×W×H(mm)	Quantity (Pcs/Carton)	
HBS	T/R	340X340X40	10000	360X360X260	60000	

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Recommended wave soldering condition					
Product	Peak Temperature	Soldering Time			
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds			



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly	
Average ramp-up rate (Tsmax to Tp)	3°C/second max.	3°C/second max.	
Preheat -Temperature Min(TS min) -Temperature Max(TS max) -Time(ts min to ts max)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds	
Time maintained above: -Temperature (TL) - Time (tL)	183°C 60-150 seconds	217°C 60-150 seconds	
Peak Temperature(TP)	240 +0/-5 °C	260 +0/-5 °C	
Time within 5°C of actual peak temperature(tp)	10-30 seconds	20-40 seconds	
Ramp down rate	6°C/second max.	6°C/second max.	
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.	

Note: All temperatures refer to topside of the package, measured on the package body surface.

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